# NSN 5962-01-367-1269

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5962-01-367-1269

## Body Length:

1.280 inches

### **Body Width:**

Between 0.220 inches and 0.310 inches

### **Body Height:**

Between 0.140 inches and 0.185 inches

#### **Maximum Power Dissipation Rating:**

1.0 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### End Application:

Eo lorops

#### Features Provided:

Hermetically sealed and burn in and monolithic and ultraviolet erasable and positive outputs

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

### Output Logic Form:

Complementary-metal oxide-semiconductor logic

#### Input Circuit Pattern:

14 input

#### Criticality Code Justification:

Feat

#### **Case Outline Source And Designator:**

D-9 mil-m-38510

#### **Current Rating Per Characteristic:**

100.00 milliamperes reverse current, dc absolute

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

#### **Capitance Rating Per Characteristic:**

6.00 input picofarads and 8.00 output picofarads

#### **Time Rating Per Chacteristic:**

45.00 nanoseconds access

#### Memory Device Type:

Eprom

#### **Special Features:**

Esd. Programmed from p/n 67268 5962-8752901la

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## AeroBase Group

## Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

Fiig:

A458a0